

2016 - 1

Inductive type impedance of high sensitivity silicon avalanche photodiodes with deeply buried micropixels

Jafarova E.¹, Sadygov Z.², Dovlatov A.¹, Aliyeva L.¹, Tapdygov E.¹

¹ Institute of Physics, Azerbaijan National Academy of Sciences,

² Joint Institute of Nuclear Research

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On features of barrier capacitance of micropixel avalanche photodiodes on different frequencies

Jafarova E.¹, Sadygov Z.^{1,2}, Ahmadov F.³, Sadygov A.³, Dovlatov A.^{1,4}, Alieva L.¹, Tapdygov E.¹, Safarov N.^{1,4}

¹ Institute of Physics, Azerbaijan National Academy of Sciences,

² Joint Institute of Nuclear Research,

³ Institute of Radiation Problems, National Academy of Sciences of Azerbaijan,

⁴ Khazar University, Baku

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